# 2SD0874, 2SD0874A (2SD874, 2SD874A)

## Silicon NPN epitaxial planar type

For low-frequency power amplification Complementary to 2SB0766 (2SB766) and 2SB0766A (2SB766A)

### ■ Features

- Large collector power dissipation P<sub>C</sub>
- ullet Low collector-emitter saturation voltage  $V_{\text{CE(sat)}}$
- Mini power type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

## ■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter                             |          | Symbol           | Rating      | Unit |  |
|---------------------------------------|----------|------------------|-------------|------|--|
| Collector-base voltage                | 2SD0874  | V <sub>CBO</sub> | 30          | V    |  |
| (Emitter open)                        | 2SD0874A |                  | 60          |      |  |
| Collector-emitter voltage             | 2SD0874  | V <sub>CEO</sub> | 25          | V    |  |
| (Base open)                           | 2SD0874A |                  | 50          |      |  |
| Emitter-base voltage (Collector open) |          | V <sub>EBO</sub> | 5           | V    |  |
| Collector current                     | $I_{C}$  | 1                | A           |      |  |
| Peak collector current                |          | $I_{CP}$         | 1.5         | A    |  |
| Collector power dissipation *         |          | P <sub>C</sub>   | 1           | W    |  |
| Junction temperature                  |          | Tj               | 150         | °C   |  |
| Storage temperature                   |          | $T_{stg}$        | -55 to +150 | °C   |  |

Note) \*: Printed circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion

# Unit: mm 4.5±0.1 1.6±0.2 1.5±0.0 1.

## Marking Symbol:

2SD0874: Z2SD0874A: Y

## ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

| Parameter                           |              | Symbol               | Conditions   | Min | Тур  | Max | Unit |
|-------------------------------------|--------------|----------------------|--|-----|------|-----|------|
| Collector-base voltage              | 2SD0874      | $V_{CBO}$            | $I_C = 10 \mu\text{A},  I_E = 0$                                   | 30  | 5    |     | V    |
| (Emitter open)                      | 2SD0874A     | OLE.                 | 60 (01) (2)  | 60  |      |     |      |
| Collector-emitter voltage           | 2SD0874      | V <sub>CEO</sub>     | $I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$                          | 25  |      |     | V    |
| (Base open)                         | 2SD0874A     |                      | d. sills ich   | 50  |      |     |      |
| Emitter-base voltage (Colle         | ctor open)   | $V_{EBO}$            | $I_E = 10 \mu\text{A},  I_C = 0$                                   | 5   |      |     | V    |
| Collector-base cutoff current (E    | mitter open) | $I_{CBO}$            | $V_{CB} = 20 \text{ V}, I_{E} = 0$                                 |     |      | 0.1 | μΑ   |
| Forward current transfer ratio *1   |              | h <sub>FE1</sub> *2  | $V_{CE} = 10 \text{ V}, I_{C} = 500 \text{ mA}$                    | 85  |      | 340 | _    |
|                                     |              | h <sub>FE2</sub>     | $V_{CE} = 5 \text{ V}, I_{C} = 1 \text{ A}$                        | 50  |      |     |      |
| Collector-emitter saturation        | voltage *1   | V <sub>CE(sat)</sub> | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$                        |     | 0.2  | 0.4 | V    |
| Base-emitter saturation vol         | tage *1      | V <sub>BE(sat)</sub> | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$                        |     | 0.85 | 1.2 | V    |
| Transition frequency                |              | $f_T$                | $V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$ |     | 200  |     | MHz  |
| Collector output capacitance        |              | C <sub>ob</sub>      | $V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$                |     |      | 20  | pF   |
| (Common base, input open circuited) |              |                      |  |     |      |     |      |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

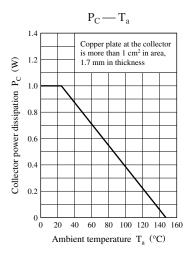
2. \*1: Pulse measurement

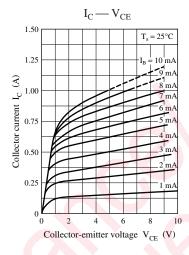
| *2: | Rank | classif | ication |
|-----|------|---------|---------|
|     |      |         |         |

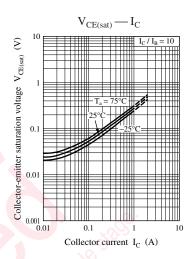
| Rank             | Q         | R          | S          |
|------------------|-----------|------------|------------|
| h <sub>FE1</sub> | 85 to 170 | 120 to 240 | 170 to 340 |

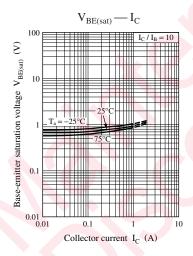
Note) The part numbers in the parenthesis show conventional part number.

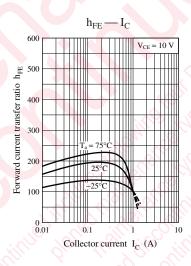
# **Panasonic**

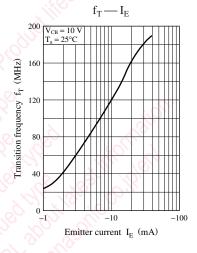


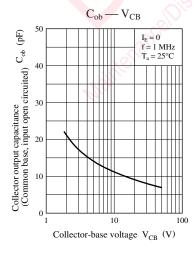


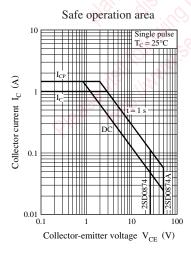












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